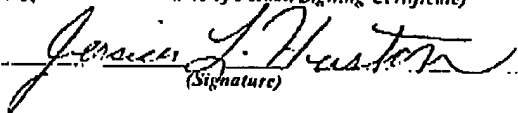


CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)			Docket No. FIS920000372US1	
Applicant(s): S. SUNDAR KUMAR IYER ET AL.				
Application No. 09/878,556	Filing Date 06/11/2001	Examiner J. CHEN	Group/Art Unit 2813	
Invention: METHOD FOR FORMING VARIABLE OXIDE THICKNESS ACROSS SEMICONDUCTOR CHIPS				
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I hereby certify that this _____ Transmittal and Amendment _____ (Identify type of correspondence) is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. 571-273-8300) on September 12, 2005 (Date)				
Jessica I. Huston (Typed or Printed Name of Person Signing Certificate)  (Signature)				
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Applicant:	S. SUNDAR KUMAR IYER, ET AL.)	
Serial No.:	09/878,556)	Group Art Unit: 2813
Filed:	June 11, 2001)	Examiner: Chen, J.
For:	METHOD OF FORMING VARIABLE OXIDE THICKNESS ACROSS SEMICONDUCTOR CHIPS)	Confirmation No.: 3210

RESPONSE TO OFFICE ACTION

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

In response to the Office Action mailed June 14, 2005, the Applicants submit the following remarks: